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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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MOS FIELD EFFECT POWER TRANSISTOR



2SK1795

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK1795 is N-channel MOS Field Effect Transistor designed for high voltage switching applications.

FEATURES

- Low On-state Resistance
 RDS(on) = 1.6 Ω (VGS = 10 V, ID = 4 A)
- Low Ciss Ciss = 1 740 pF TYP.
- Built-in G-S Gate Protection Diode
- High Avalanche Capability Ratings

QUALITY GRADE

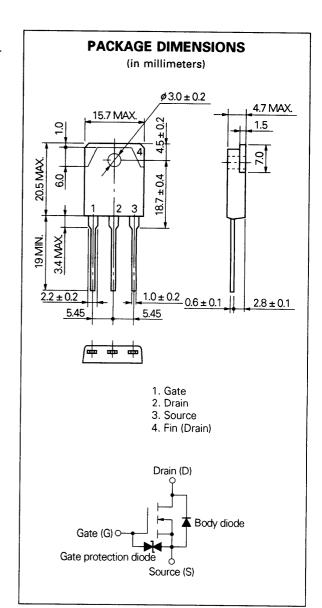
Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Drain to Source Voltage	Voss	900	V
Gate to Source Voltage	Vgss	±30	V
Drain Current (DC)	ID(DC)	±8.0	Α
Drain Current (pulse)	D(pulse)#	±16	Α
Total Power Dissipation (Tc = 25 °C)	PT	140	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current	las**	8.0	Α
Single Avalanche Energy	Eas**	38	mJ

- * PW \leq 10 μ s, Duty Cycle \leq 1 %
- ** Starting Tch = 25 °C, Rg = 25 Ω , Vgs = 20 V \rightarrow 0



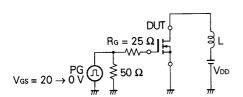


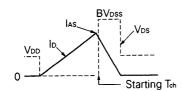


ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

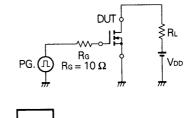
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	Ros(on)		1.3	1.6	Ω	Vgs = 10 V, lp = 4 A
Gate to Source Cutoff Voltage	Vgs(off)	2.5		3.5	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	yfs	1.0	6.0		s	VDS = 20 V, ID = 4 A
Drain Leakage Current	Ipss			100	μΑ	V _D s = 900 V, V _G s = 0
Gate to Source Leakage Current	Igss			±10	μΑ	Vgs = ±30 V, Vps = 0
Input Capacitance	Ciss		1740		pF	V _{DS} = 10 V
Output Capacitance	Совя		285		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		110		pF	f = 1 MHz
Turn-On Delay Time	td(on)		30		ns	$V_{GS} = 10 \text{ V}$ $V_{DD} = 150 \text{ V}$ $I_D = 4 \text{ A}, R_G = 10 \Omega$ $R_L = 37.5 \Omega$
Rise Time	tr		40		ns	
Turn-Off Delay Time	td(off)		150		ns	
Fall Time	tr		35		ns	
Total Gate Charge	QG		66		nC	V _{GS} = 10 V I _D = 8 A V _{DD} = 720 V
Gate to Source Charge	Qgs		10		nC	
Gate to Drain Charge	QGD		22		nC	
Diode Forward Voltage	VF(S - D)		0.9		V	IF = 8 A, VGS = 0
Reverse Recovery Time	trr		700		ns	I _F = 8 A di/dt = 50 A/μs
Reverse Recovery Charge	Qrr		5.4		μС	

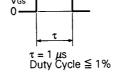
Test Circuit 1: Avalanche Capability

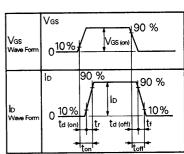




Test Circuit 2: Switching Time





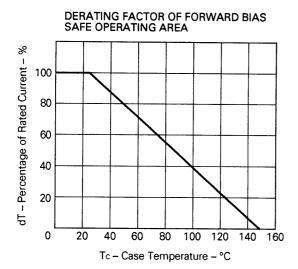


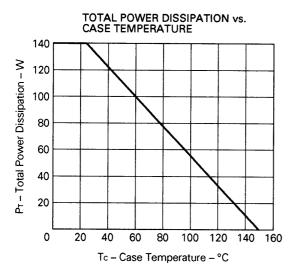
Test Circuit 3: Gate Charge

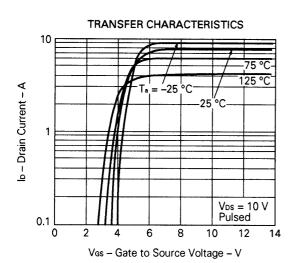
$$\begin{array}{c|c} & \text{DUT} \\ & \text{Ig} = 2 \text{ mA} \\ \hline \text{PG.} & \begin{array}{c} \\ \\ \\ \end{array} \end{array} \begin{array}{c} \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \end{array} \end{array} \begin{array}{c} \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \end{array} \begin{array}{c} \\ \\ \\ \\ \\$$

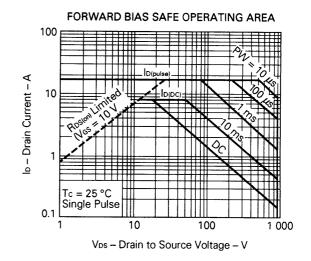


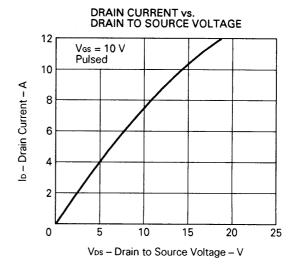
TYPICAL CHARACTERISTICS (Ta = 25 °C)

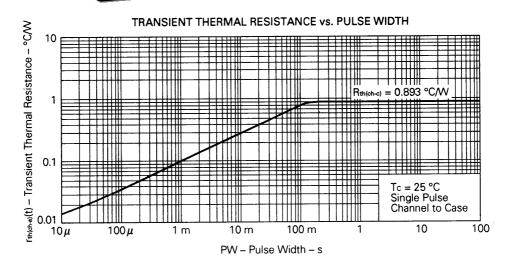


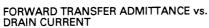


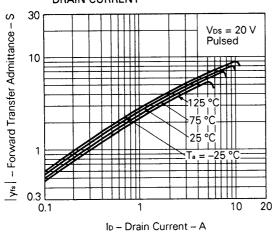




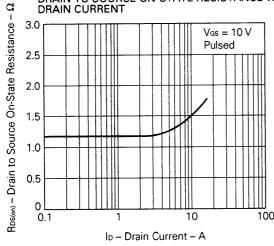




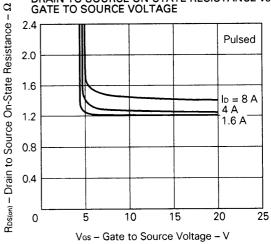




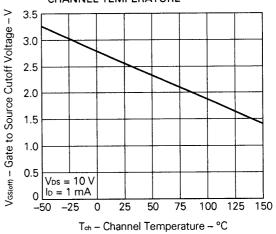
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

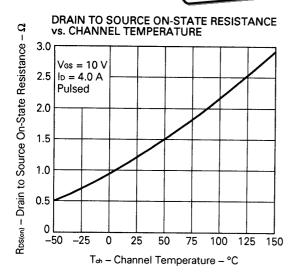


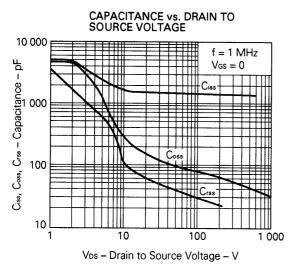
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

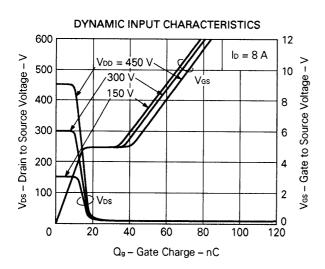


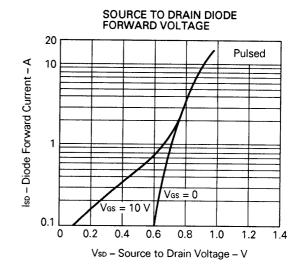
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

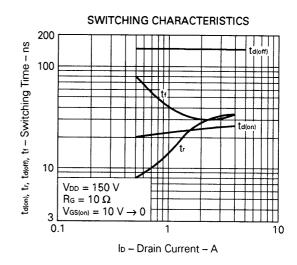


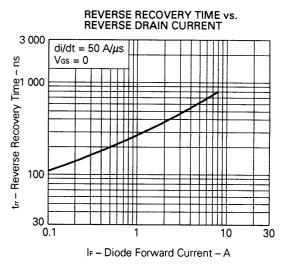




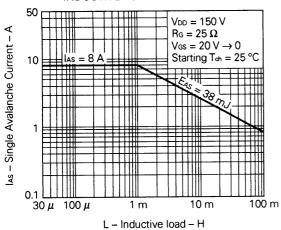




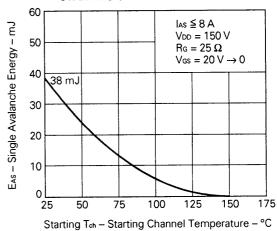




SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



SINGLE AVALANCHE ENERGY vs. STARTING CHANNEL TEMPERATURE



6



Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207



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